



Fabrication of ZnO Nanowire Arrays for Hybrid Photovoltaic Applications

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Goals and Summary

Primary goals:

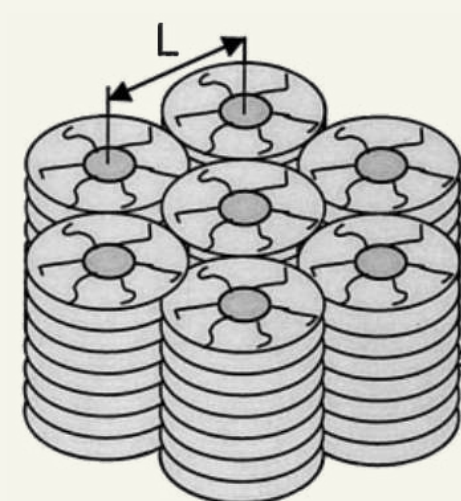
- Controlled fabrication of uniform ZnO nanowire arrays on Si substrates via chemical vapor deposition with vapor-liquid-solid (VLS) mechanism
- Optimization of growth parameters
- Fabrication of hybrid photovoltaic cells using ZnO and smectic octylcyanobiphenyl (8CB) liquid crystals

Summary of work:

- Achieved reproducible growth of ZnO nanowire arrays on Si in horizontal tube furnace
- Determined effect of various growth parameters on resulting arrays
- Observed enhanced optical absorption when nanowires and liquid crystal are combined
- Nanowires seem to grow by non-VLS mechanism

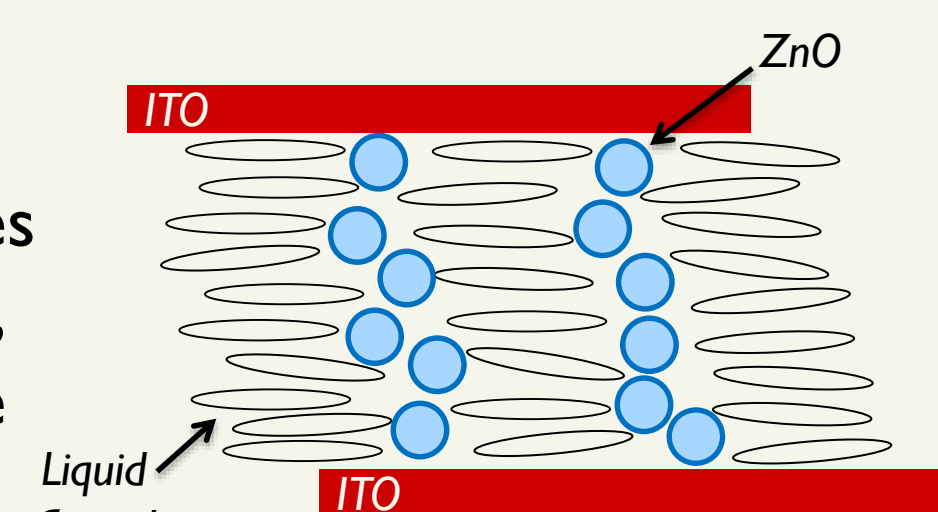
Motivation

- Combination of inorganic nanostructures and organic material can improve absorption and mechanical properties
 - Dye-sensitized solar cells [1]
 - Flexible ZnO/P3HT bulk heterojunctions [2]

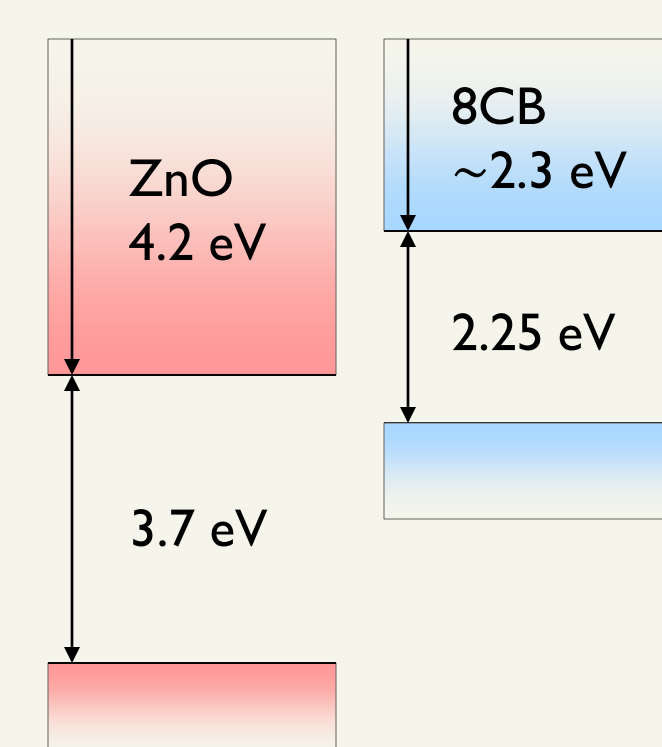
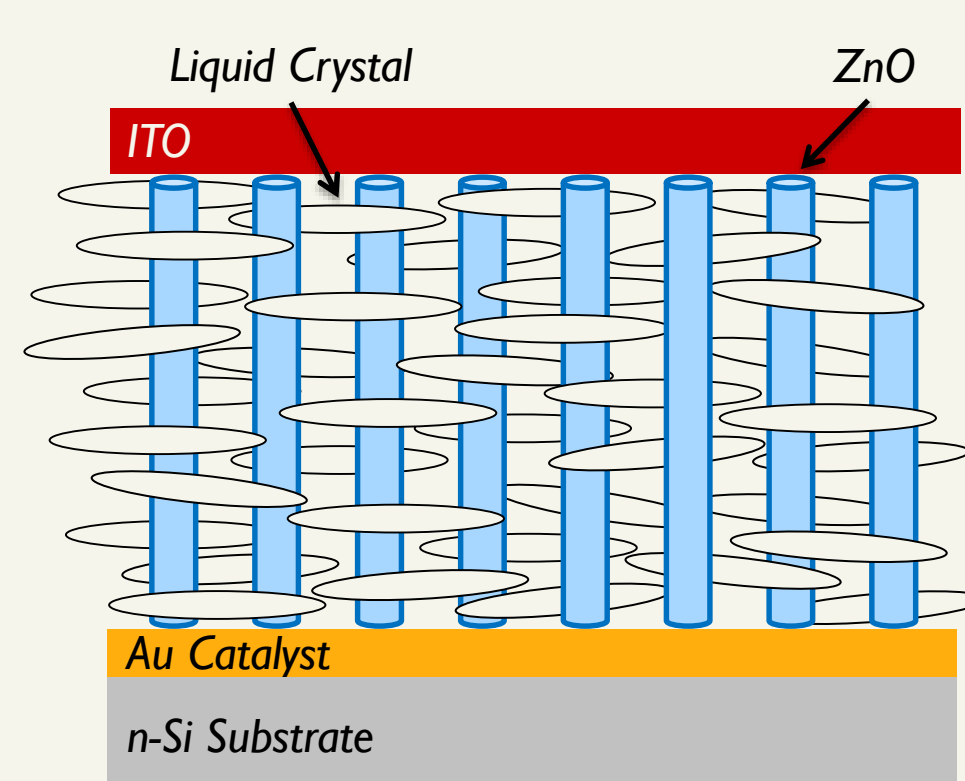


- Liquid crystal photovoltaics can self-organize, enhancing charge transfer along axis of orientation [3]

- Incorporating ZnO nanoparticles enhances order of liquid crystal, greatly improving hole mobility [4]
- Could a continuous inorganic pathway (nanowires) have the same effect?**
 - Enhanced hole conduction from liquid crystals
 - Enhanced electron conduction in nanowires
- Can we control the morphology of ZnO nanowire arrays?**



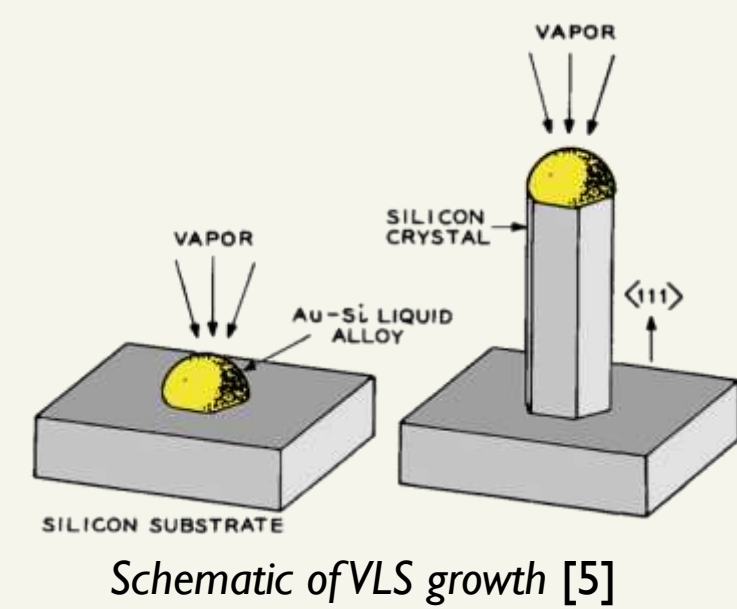
Hybrid Photovoltaic Design



- Use smectic octylcyanobiphenol (8CB) to investigate ordering between liquid crystal and nanowires
 - Compare to ordering with nanoparticles
- Expected band structure
 - ZnO: electron conductor
 - 8CB: hole conductor

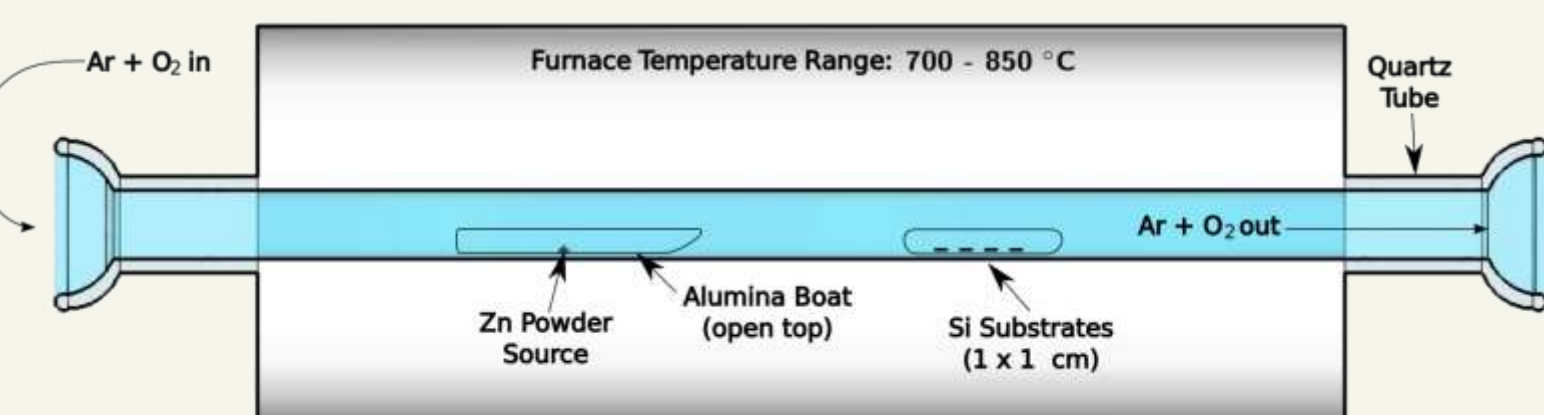
Methods & Experimental Parameters

- Vapor-liquid-solid nanowire growth method [5]
 - Chemical vapor deposition technique
 - Catalyst metal thin film
 - Metal droplet acts as seed for nanowire
- Has been used successfully for ZnO aligned nanowire array synthesis [6,7]
 - Zn powder and O₂ gas source materials
 - Results are strongly dependent on experimental conditions and particular sample geometry [8]



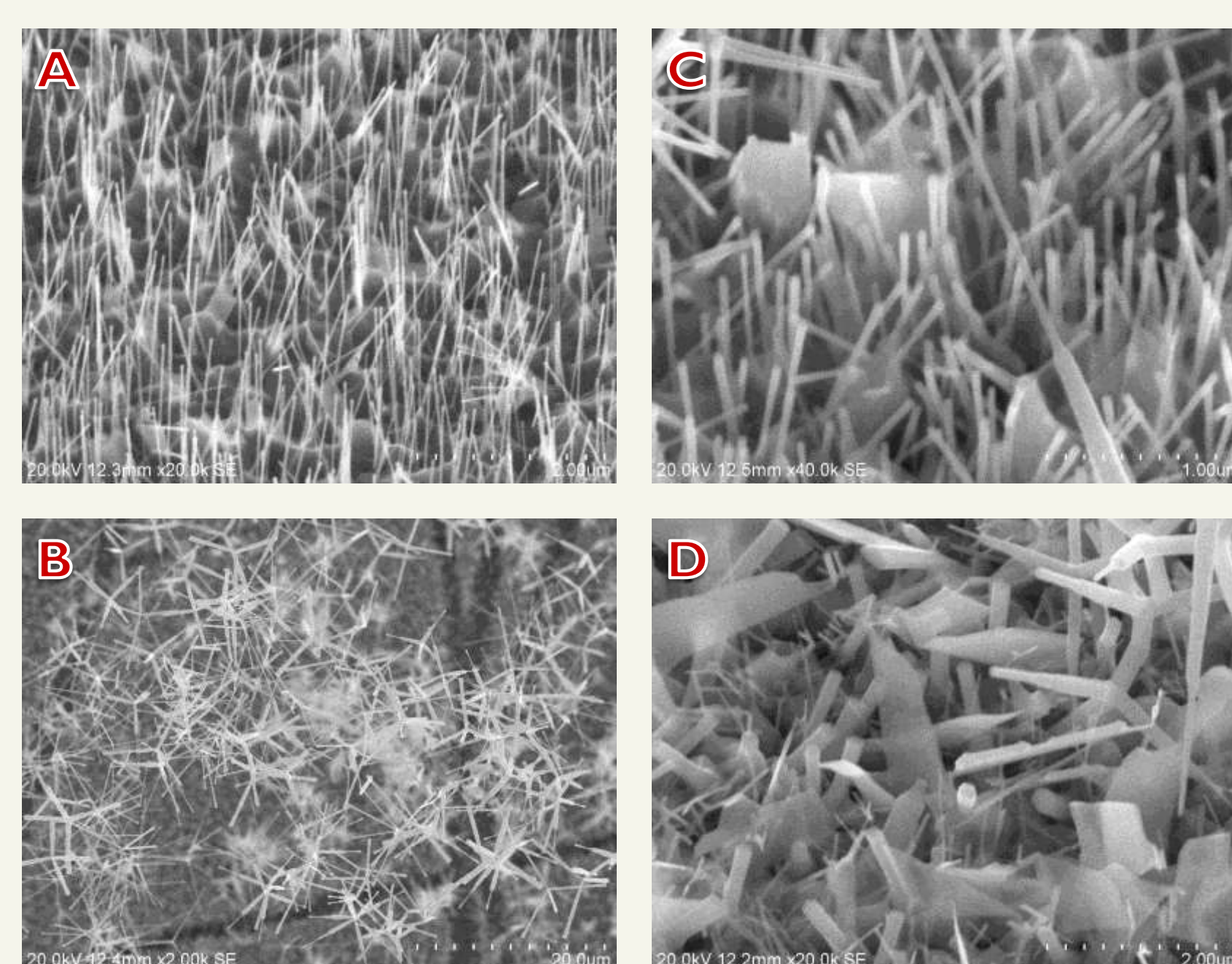
- Growth parameters investigated in this study:
 - Total gas flow rate (O₂ + Ar carrier gas)
 - Relative gas flow rates (Ar:O₂ ratio)
 - Timing of gas release
 - Mass of Zn source powder
 - Geometry of interior components
 - Affects substrate temperature and local P_{O₂} and P_{Zn(v)}

Experimental Setup



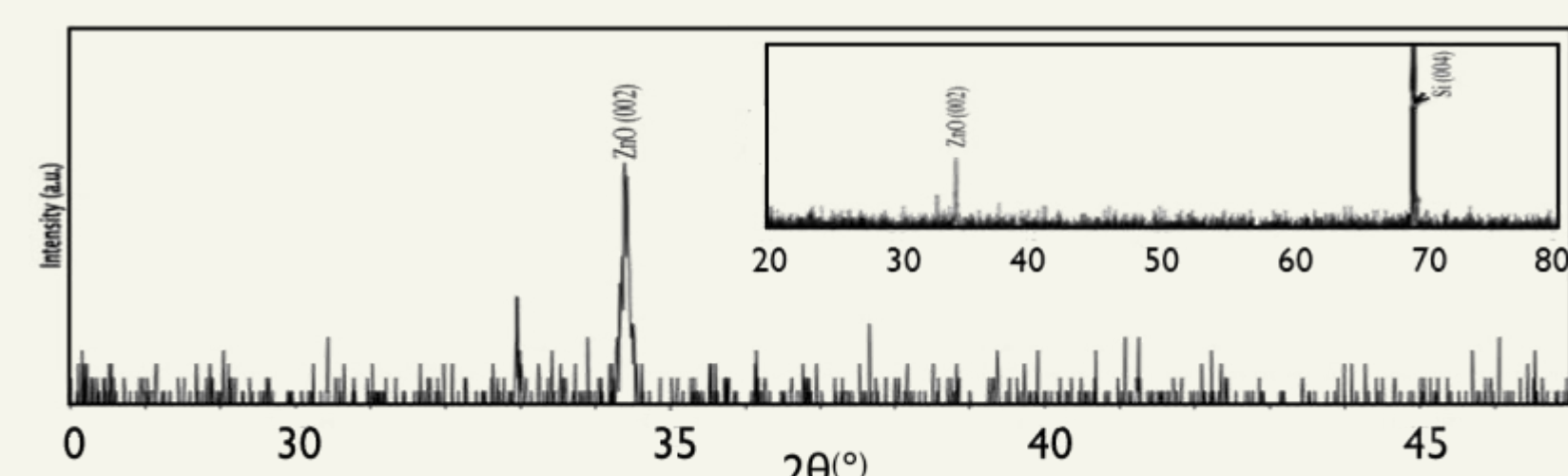
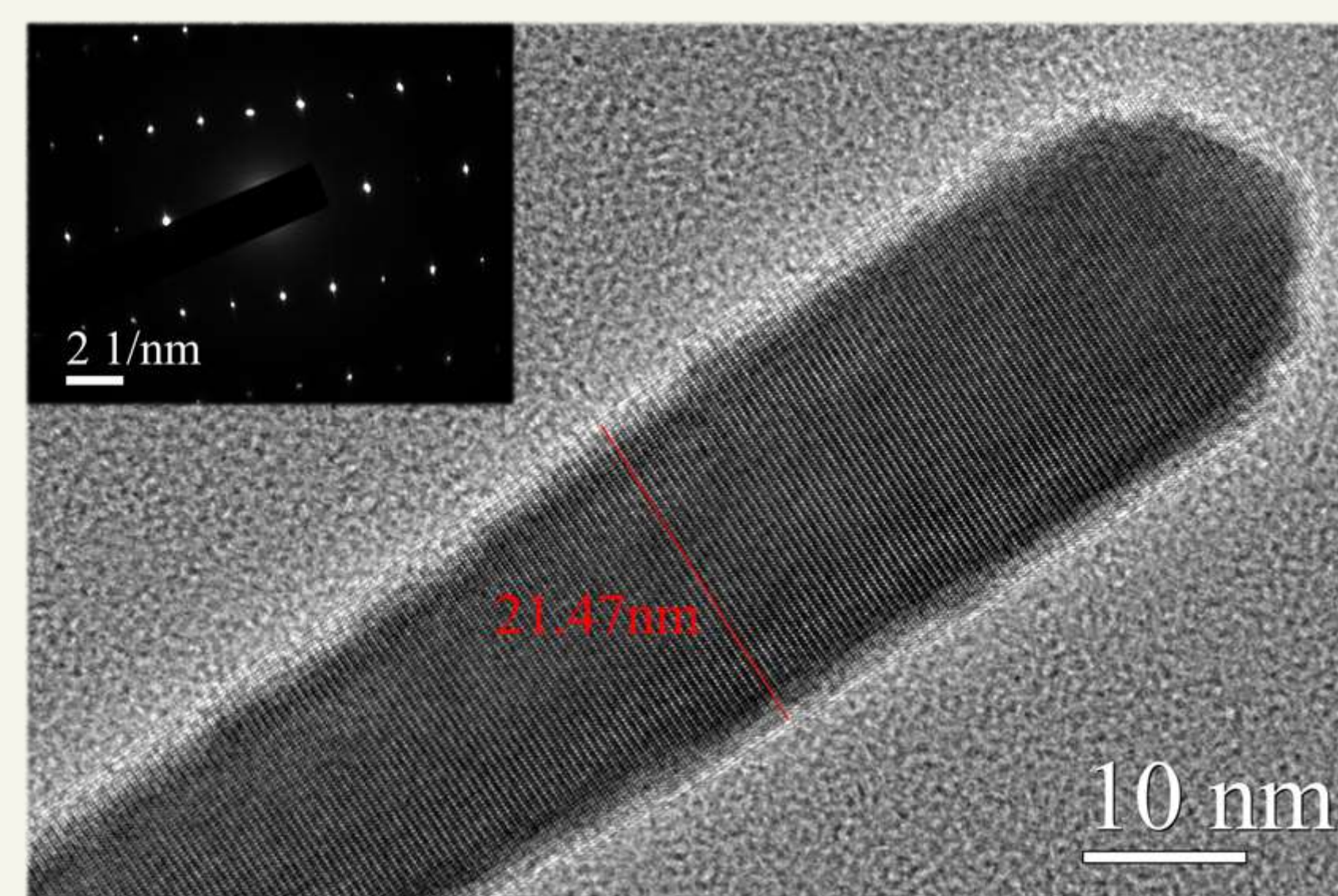
- Horizontal tube furnace (P: 1 atm)
- Source Zn and substrates in alumina boats
- Au thin film catalyst layer (2 nm)
- Si (001) wafer with native SiO₂ oxide layer
- Inert Ar carrier gas
- T = 700 – 850°C

Common Nanowire Array Growth Morphologies



- A. Uniform diameters; narrow wires grow from textured ZnO film
- B. Tetrapod "overgrowth" extended above nanowire growth
- C. Thicker diameters; inferior alignment; non-uniform shape and size
- D. Mix of "nanobelts," "nanorods," tetrapods, and "nanoribbons"

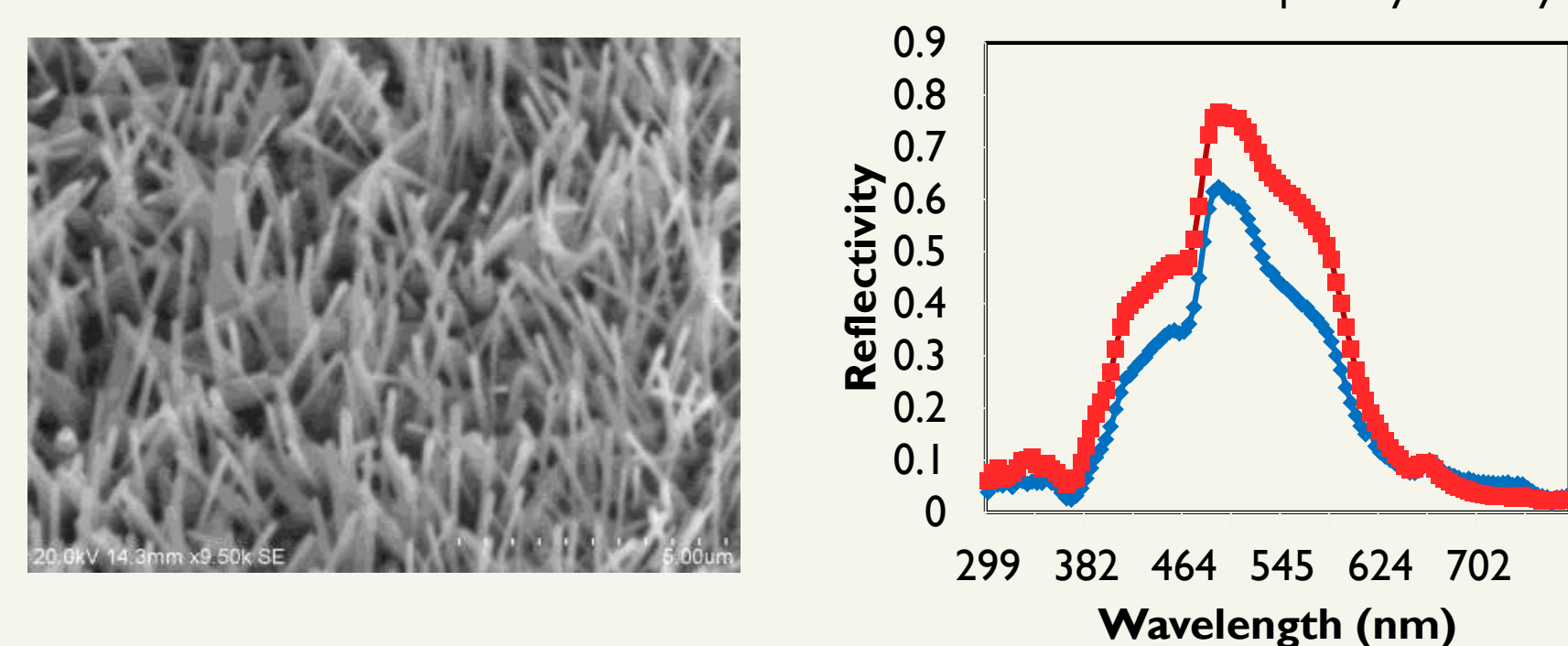
Nanowire Array Crystallinity



- HRTEM and XRD:
 - Nanowires are high quality and single-crystalline
 - Grow along [0001] direction
 - Fairly uniform diameter
 - No evidence for VLS growth (metal at tip)

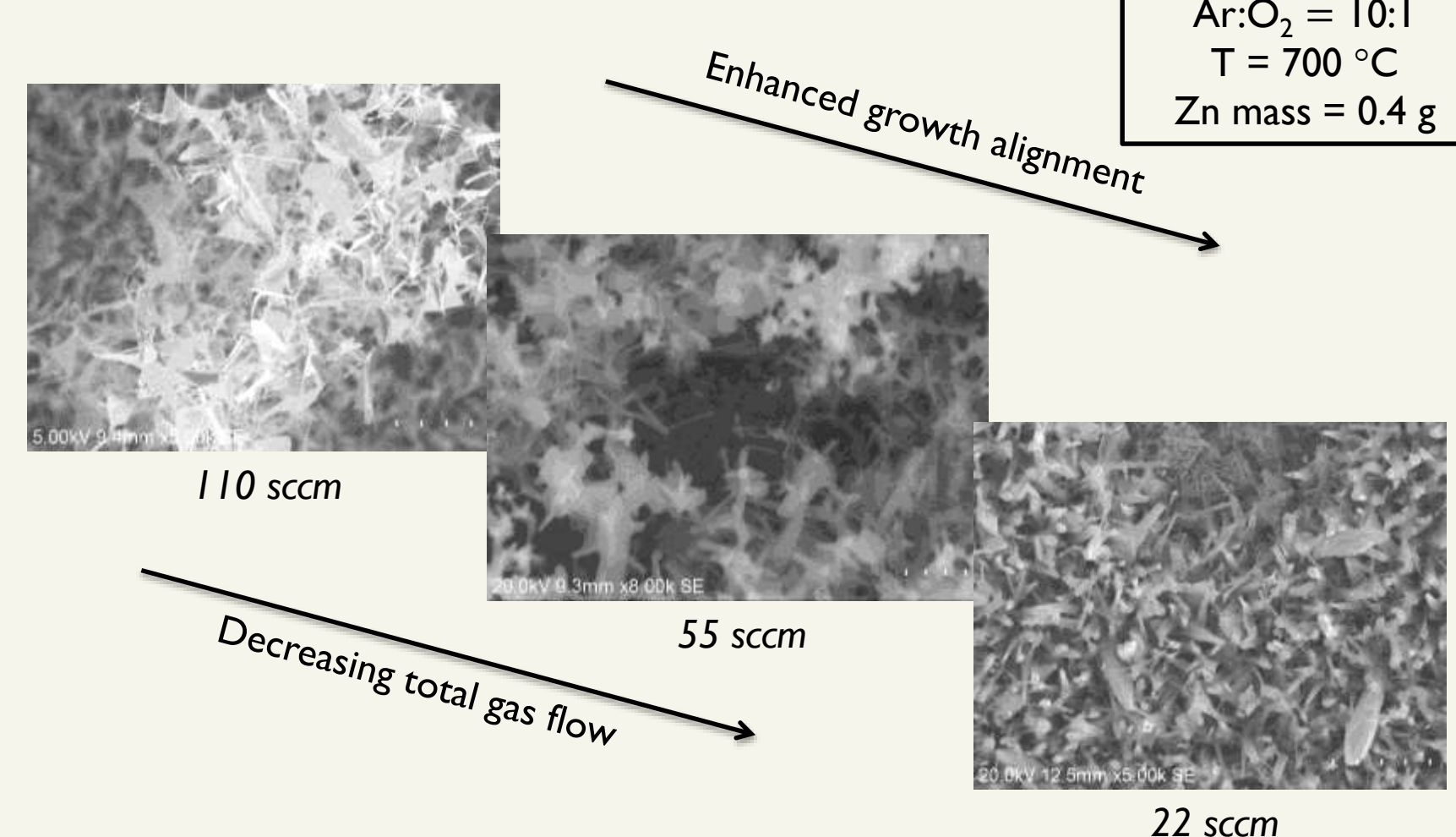
Reflectivity: Nanowires with Liquid Crystal

- Preliminary reflectivity measurements
 - Using poorly-aligned but uniform 200 nm diameter array
 - Measure pure liquid crystal and hybrid system
 - Witnessed decreased reflection
 - ↓ reflection = ↑ absorption
 - Both liquid crystal and nanowires contribute to photoabsorption



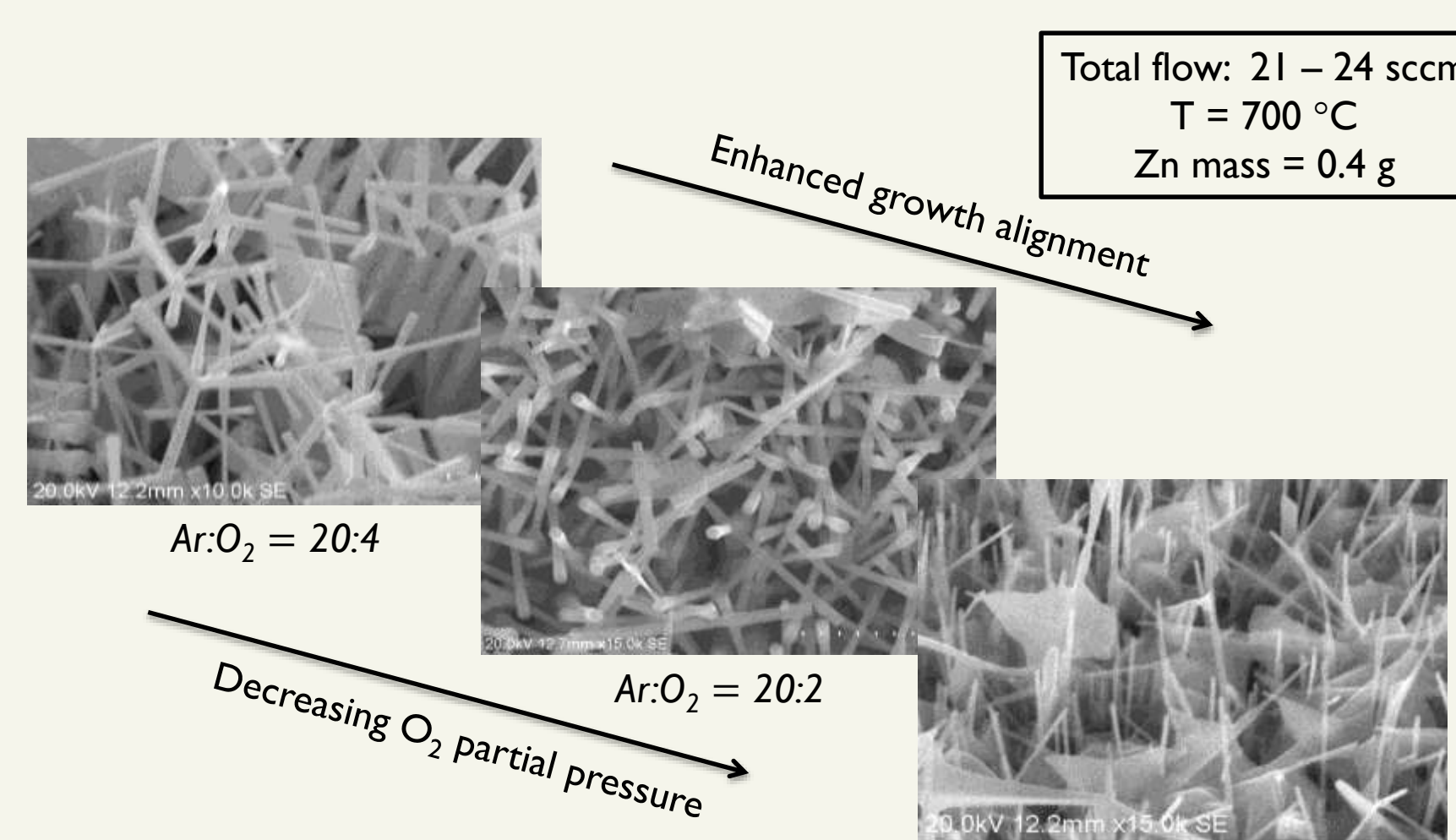
Effect of Growth Conditions

Total Gas Flow:



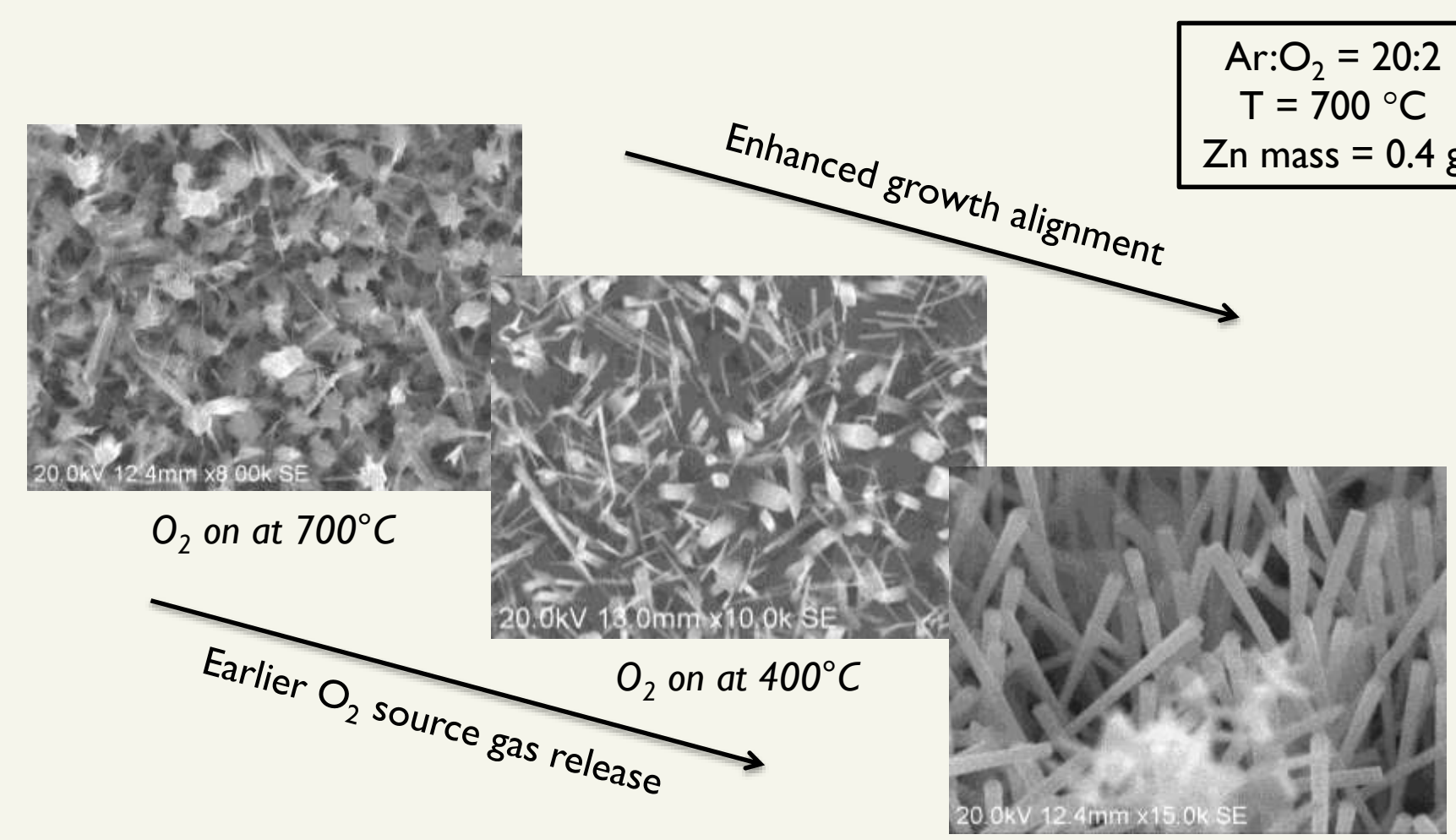
- Lower flow rates decreases branching and allows for more controlled growth

Relative Gas Flow Ratio:



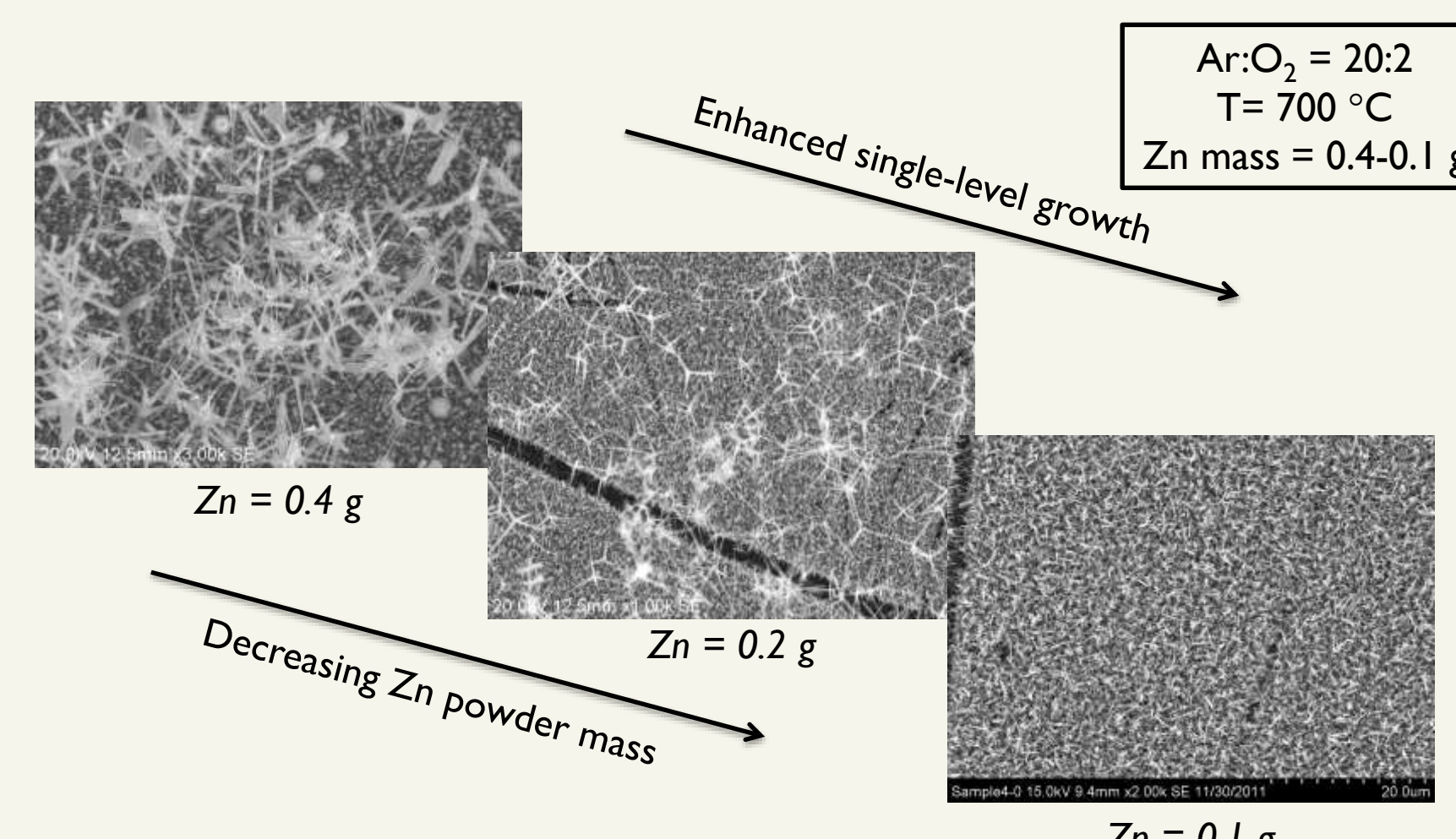
- Lower oxygen partial pressure suppresses tetrapod overgrowth and encourages vertical wire alignment

Oxygen Gas Release Time:



- Earlier gas release improves uniformity and nanowire shape/alignment → steady state growth
- Oxidation of source before melting can prevent Zn vapor formation if not enough Zn source used

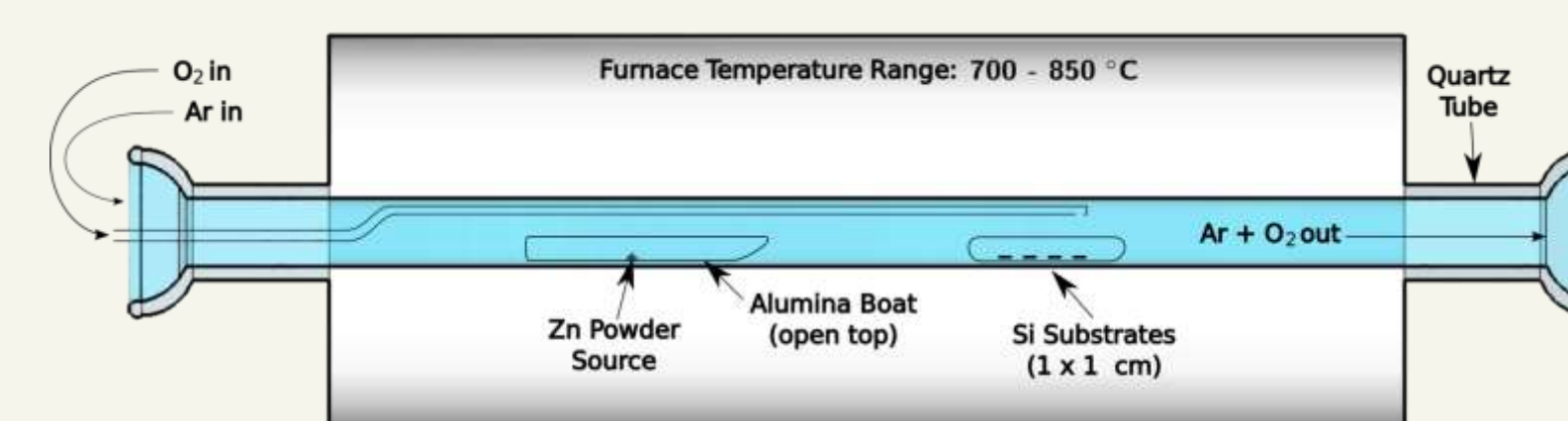
Zn Source Mass:



- Reduced source mass discourages top-level overgrowth and improves uniformity, to a point
 - Too little Zn source can cause early oxidation and prevent evaporation into Zn vapor

Alternate Synthesis Design

- When using low source mass (0.2 g and below) and earlier O₂ gas release, Zn source has tendency to oxidize with a skin, preventing evaporation
- Introducing O₂ directly at substrate allows for finer control of growth conditions:
 - Geometry and local P_{O₂} can be finely controlled
 - Oxidation of source is prevented
 - Greater flexibility in localized conditions
- Design after J. Park et al. [9]:
 - "Showerhead" O₂ delivery
 - Releases O₂ immediately to substrate



Preliminary Results:

- Showerhead prevents source oxidation
- Did not immediately observe VLS as in [9]
- Changing internal geometry significantly affected growth results (need further optimization)

Conclusions

- Setup reproducibly grows ZnO nanowire arrays
 - Vertical alignment needs improvement
 - VLS mechanism not active
- Growth results are heavily dependent on a wide range of experimental parameters
 - Localized conditions greatly affect results, e.g., Zn vapor pressure, O₂ partial pressure
- Most promising conditions:
 - Lowest possible flow rates (less turbulence)
 - Lowest P_{O₂} (lowers oxidation rate)
 - Earlier O₂ release (steady state conditions)
 - Less Zn source (reduces Zn vapor saturation)
- Approaching optimized conditions for VLS growth
 - "Showerhead" O₂ delivery shows great promise
- Optical absorption is higher when nanowires are combined with liquid crystal

Future Work

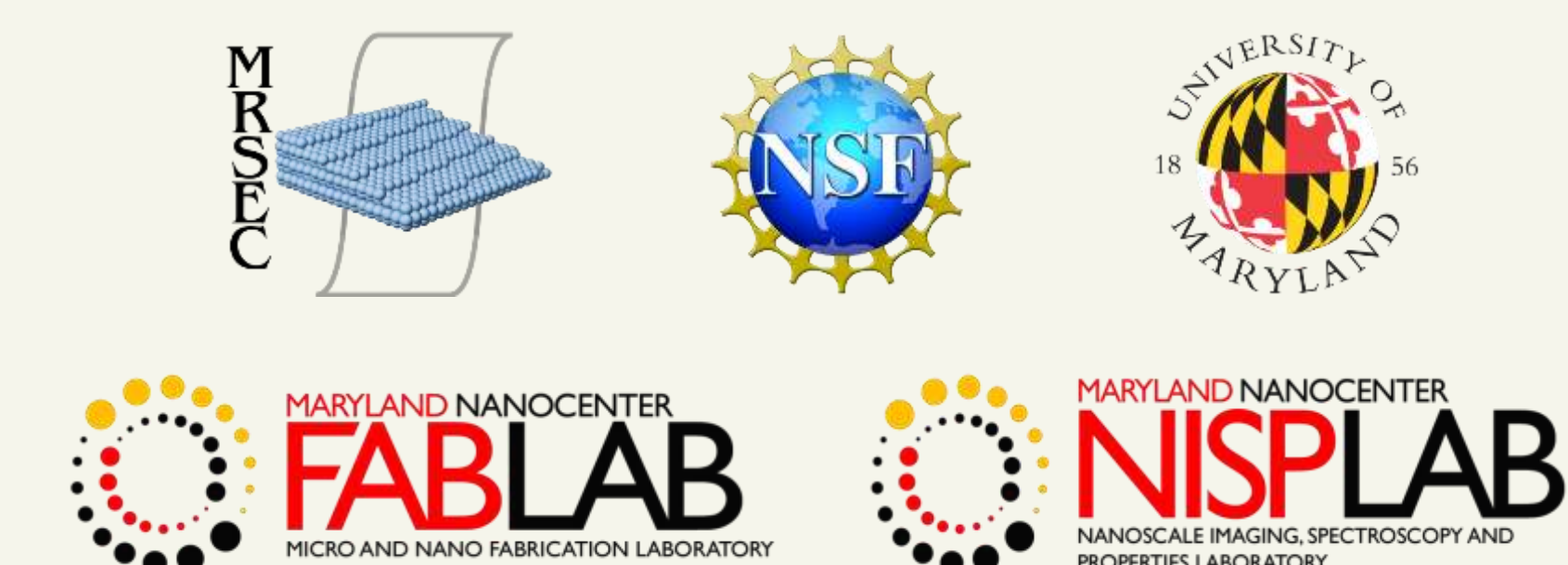
- Further investigation of new furnace geometry
- Characterize effect of other growth parameters:
 - Total chamber pressure
 - Substrate/source temperature
 - Distance between source and substrate
 - Growth time and furnace heating rate
- Fabricate proof-of-concept devices
- Measure photoconductivity of ZnO nanowires with liquid crystal
- Characterize liquid crystal orientation effect of nanowires relative to ZnO nanoparticles

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Acknowledgments

- This work was supported in part by the National Science Foundation under the University of Maryland MRSEC DMR 05-20471.
- We acknowledge the support of the Maryland NanoCenter and its FabLab in the fabrication of the nanowire arrays, including Thomas Loughran and Jonathan Hummel.
- We also acknowledge the support of the Maryland Nanocenter and its Nisplab. The Nisplab is supported in part by the NSF as a MRSEC Shared Experimental Facility.



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